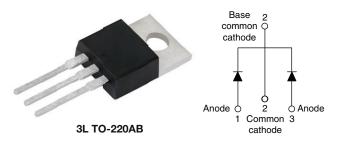


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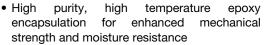
High Performance Schottky Rectifier, 2 x 30 A



PRIMARY CHARCTERISTICS								
I _{F(AV)} 2 x 30 A								
V_{R}	35 V, 40 V, 45 V							
V _F at I _F	0.57 V							
I _{RM} max.	40 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	27 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform (per device)	60	Α					
V _{RRM}		35 to 45	V					
I _{FRM}	T _C = 142 °C (per leg)	60	^					
I _{FSM}	t _p = 5 μs sine	2600	А					
V _F	30 A _{pk} , T _J = 125 °C	0.57	V					
TJ	Range	-65 to +175	°C					

VOLTAGE RATINGS									
PARAMETER SYMBOL VS-61CTQ035-M3 VS-61CTQ040-M3 VS-61CTQ045-M3 UNITS									
Maximum DC reverse voltage	V_R	35	40	45	W				
Maximum working peak reverse voltage	V _{RWM}	ან	40	45	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS			
Maximum average per le		$I_{F(AV)}$ $T_C = 142$ °C, rated V_R		T 140 %0		30		
forward current per device	F(AV)			60				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 142 °C		60	Α			
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	2600				
surge current per leg	IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	350				
Non-repetitive avalanche energy per le	E _{AS}	$T_{J} = 25 ^{\circ}\text{C}, I_{AS} = 4 \text{A}, L = 3.4 \text{mH}$		27	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		4	Α			



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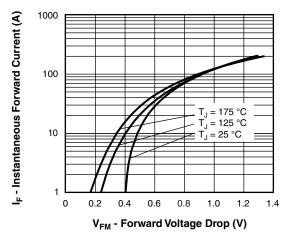
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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS			
		30 A	T _J = 25 °C	0.57	0.61			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	60 A	11 = 23 0	0.72	0.76	V		
Maximum forward voltage drop	VFM (1)	30 A	T _{.1} = 125 °C	0.53	0.57			
		60 A	1] = 123 0	0.70	0.74			
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.06	1	mA		
Maximum instantaneous reverse current		T _J = 125 °C	nated DC voltage	21	40	IIIA		
Maximum junction capacitance	C_{T}	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		19	00	pF		
Typical series inductance	L _S	Measured from top of terminal to mounting plane			.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-65 to +175	°C				
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.2	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50					
Approximate weight				g				
Approximate weight			0.07	OZ.				
Mounting torque		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque maximum	1	Non-lubricated trireads	12 (10)	(lbf ⋅ in)				
			61CTQ035					
Marking device		Case style 3L TO-220AB	61CTQ040					
			61CTQ045					



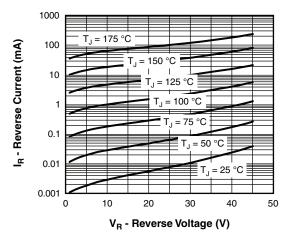


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

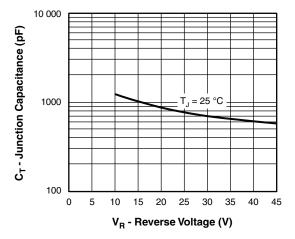


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

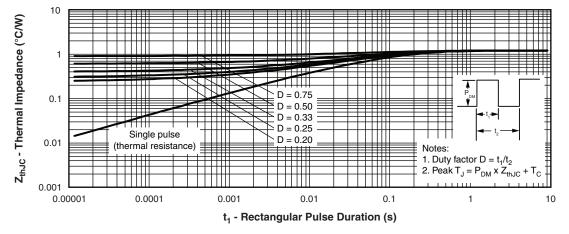


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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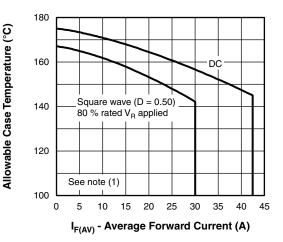


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

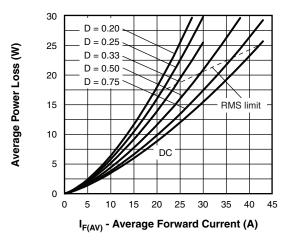


Fig. 6 - Forward Power Loss Characteristics

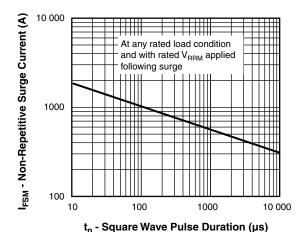


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

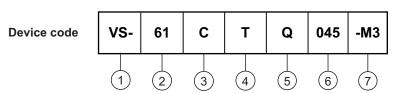
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

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ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

3 - Circuit configuration

C = common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

035 = 35 V

6 - Voltage ratings

040 = 40 V 045 = 45 V

7 - Voltage ratings —

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-61CTQ035-M3	50	1000	Antistatic plastic tube						
VS-61CTQ040-M3	50	1000	Antistatic plastic tube						
VS-61CTQ045-M3	50	1000	Antistatic plastic tube						

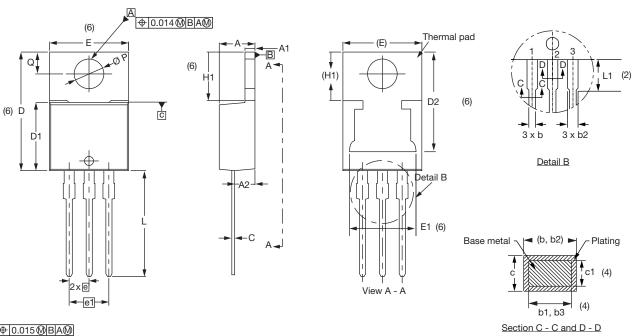
LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?96154</u>						
Part marking information	www.vishay.com/doc?95028					



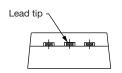
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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